TOSHIBA BI-DIRECTIONAL TRIODE THYRISTOR SILICON PLANAR TYPE

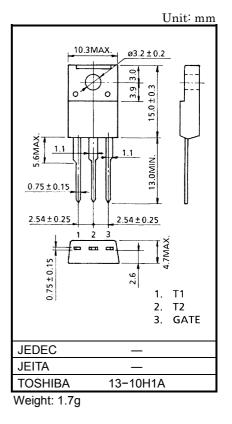
SM10LZ47

AC POWER CONTROL APPLICATIONS

- Repetitive Peak Off-State Voltage : V_{DRM} = 800V
- R.M.S. On–State Current : I_T (RMS) = 10A
- High Commutation (dv / dt)
- Isolation Voltage : V
- : $V_{ISOL} = 1500 V AC$

MAXIMUM RATINGS

CHARACTERISTIC	SYMBOL	RATING	UNIT	
Repetitive Peak Off-State Voltage	V _{DRM}	800	V	
R.M.S On-State Current (Full Sine Waveform)	I _{T (RMS)}	10	А	
Peak One Cycle Surge On-State	ITOL	100 (50Hz)	A	
Current (Non-Repetitive)	ITSM	110 (60Hz)		
I ² t Limit Value	l ² t	50	A ² s	
Critical Rate of Rise of On-State Current (Note)	di / dt	50	Α / μs	
Peak Gate Power Dissipation	P _{GM}	5	W	
Average Gate Power Dissipation	P _{G (AV)}	0.5	W	
Peak Gate Voltage	V _{FGM}	10	V	
Peak Gate Current	I _{GM}	2	А	
Junction Temperature	Tj	-40~125	°C	
Storage Temperature Range	T _{stg}	-40~125	°C	
Isolation Voltage (AC, t = 1min.)	VISOL	1500	V	



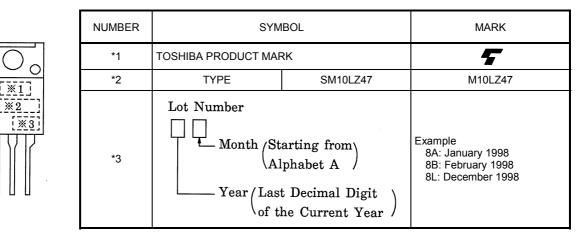
Note: di / dt test condition $V_{DRM} = 0.5 \times \text{Rated}, I_{TM} \le 15\text{A}, t_{dW} \ge 10\mu\text{s},$

 $t_{gr} \le 250$ ns, $i_{gp} = I_{GT} \times 2.0$

ELECTRICAL CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC		SYMBOL	TEST CONDITION		MIN	TYP.	MAX	UNIT
Repetitive Peak Off-State Current		I _{DRM}	V _{DRM} = Rated		_	_	20	μA
Gate Trigger Voltage	I	V _{GT}	V _D = 12V, R _L = 20Ω	T2 (+) , Gate (+)		_	1.5	V
	П			T2 (+) , Gate (−)	_	-	1.5	
	Ш			T2 (-) , Gate (-)		_	1.5	
Gate Trigger Current	I	I _{GT}	V _D = 12V, R _L = 20Ω	T2 (+) , Gate (+)		_	30	mA
	П			T2 (+) , Gate (−)		_	30	
	Ш			T2 (-) , Gate (-)		_	30	
Peak On-State Voltage		V _{TM}	I _{TM} = 15A			_	1.5	V
Gate Non-Trigger Voltage		V _{GD}	V _D = Rated, Tc = 125°C		0.2	_	_	V
Holding Current		Ι _Η	V _D = 12V, I _{TM} = 1A			_	50	mA
Thermal Resistance		R _{th (j−c)}	Junction to Case, AC			_	3.4	°C/W
Critical Rate of Rise of Off-State Voltage dv / dt		V _{DRM} = 600V, T _j = 125°C Exponential Rise		_	300	_	V / µs	
Critical Rate of Rise of Off–State Voltage $(dv / dt) c$ $V_{DRM} = 400V, T_j = 125^{\circ}C$ at Commutation $(dv / dt) c = -5.5A / ms$		Г _ј = 125°С 5А / ms	10	_	_	V / µs		

MARKING



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